



DATA SHEET

SEMICONDUCTOR

UF8A THRU UF8M

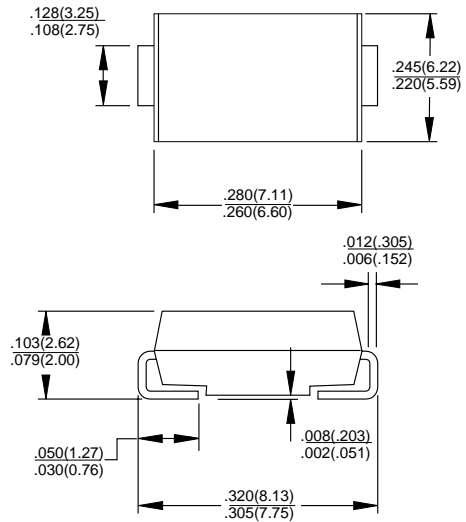
SURFACE MOUNT ULTRAFAST RECTIFIER VOLTAGE - 50 to 1000 Volts CURRENT - 8.0 Amperes



FEATURES

- For surface mounted applications
- Low profile package
- Built-in strain relief
- Easy pick and place
- Ultrafast recovery times for high efficiency
- Plastic package has Underwriters Laboratory Flammability Classification 94V-O
- Glass passivated junction
- High temperature soldering:
260 °C /10 seconds at terminals
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- Pb free product at available : 99% Sn above meet RoHS environment substance directive request

SMC/DO-214AB Unit:inch(mm)



MECHANICAL DATA

- Case: JEDEC DO-214AB molded plastic
Terminals: Solder plated, solderable per MIL-STD-750, Method 2026
- Method 2026
- Polarity: Indicated by cathode band
- Standard packaging: 16mm tape (EIA-481)
Weight: 0.007 ounce, 0.21 gram

CHARACTERISTICS	SYMBOL	UF8A	UF8B	UF8D	UF8G	UF8J	UF8K	UF8M	UNIT
Maximum Recurrent Peak Reverse Voltage	VRRM	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	VRMS	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	VDC	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current @TL =75°C	I(AV)	8.0							A
Peak Forward Surge Current 8.3ms single half sine-wave super imposed on rated load (JEDEC METHOD)	IFSM	100							A
Maximum forward Voltage at 8.0A DC	VF	1.0		1.3	1.5	1.7		V	
Maximum DC Reverse Current @TJ =25°C at Rated DC Blocking Voltage @TJ =100°C	IR	10							uA
Maximum Reverse Recovery Time (Note 1)	TRR	50				75			ns
Typical Junction Capacitance (Note 2)	CJ	20				10			pF
Typical Thermal Resistance (Note 3)	RθJL	30							°C/W
Operating Temperature Range	TJ	-55 to +150							°C
Storage Temperature Range	TSTG	-55 to +150							°C

- NOTES : 1.Reverse Recovery Test Conditions :IF=0.5A,IR=1.0A,IRR=0.25A.
2.Measured at 1.0MHz and applied reverse voltage of 4.0V DC.
3.Thermal Resistance junction to Lead.

RATING AND CHARACTERISTIC CURVES

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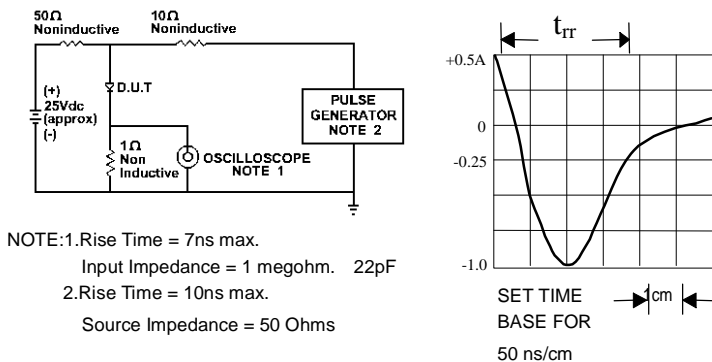


Fig. 1-REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM

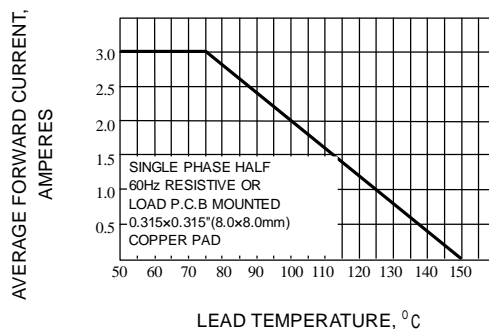


Fig. 2-MAXIMUM AVERAGE FORWARD CURRENT RATING

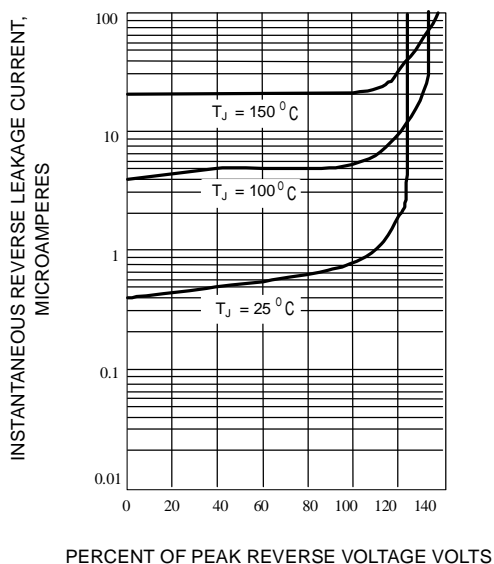


Fig. 3-TYPICAL REVERSE CHARACTERISTICS

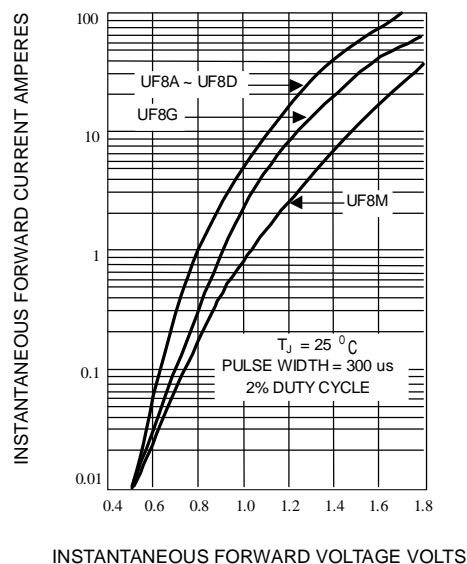


Fig. 4-TYPICAL FORWARD CHARACTERISTICS

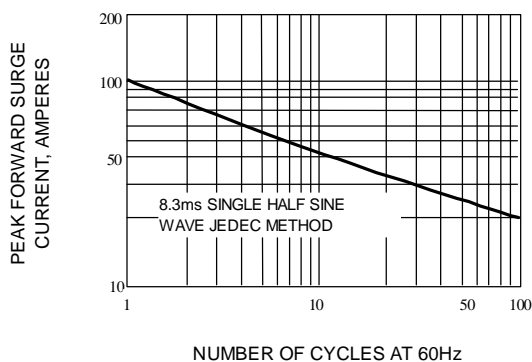


Fig. 5-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

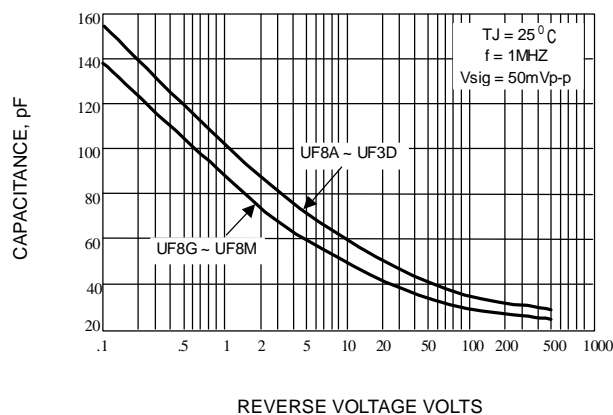


Fig. 6-TYPICAL JUNCTION CAPACITANCE